

SN74ALS2232A

64 × 8 ASYNCHRONOUS FIRST-IN, FIRST-OUT MEMORY

SCAS248 – FEBRUARY 1988 – REVISED MARCH 1990

- Independent Asynchronous Inputs and Outputs
- 64 Words by 8 Bits
- Data Rates From 0 to 40 MHz
- Fall-Through Time . . . 20 ns Typical
- 3-State Outputs

description

This 512-bit memory uses advanced low-power Schottky IMPACT-X™ technology and features high speed and fast fall-through times. It is organized as 64 words by 8 bits.

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The function is used as a buffer to couple two buses operating at different clock rates. This FIFO is designed to process data at rates from 0 to 40 MHz in a bit-parallel format, word by word.

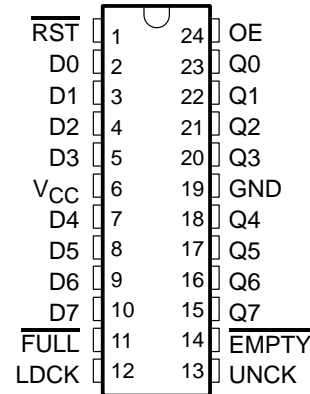
Data is written into memory on a low-to-high transition of the load clock (LDCK) input and is read out on a low-to-high transition of the unload clock (UNCK) input. The memory is full when the number of words clocked in exceeds by 64 the number of words clocked out. When the memory is full, LDCK signals have no effect on the data residing in memory. When the the memory is empty, UNCK signals have no effect.

Status of the FIFO memory is monitored by the FULL and EMPTY output flags. The FULL output is low when the memory is full and high when the memory is not full. The EMPTY output is low when the memory is empty and high when it is not empty.

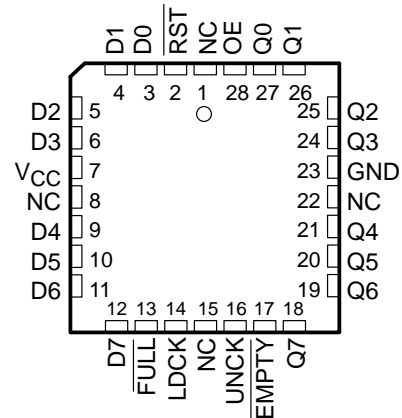
A low level on the reset (RST) input resets the internal stack control pointers and also sets EMPTY low and FULL high. The outputs are not reset to any specific logic levels. The first low-to-high transition on LDCK, either after a RST pulse or from an empty condition, causes EMPTY to go high and the data to appear on the Q outputs. The first word does not have to be unloaded. Data outputs are noninverting with respect to the data inputs and are at a high-impedance state when the output-enable (OE) input is low. The OE input does not effect either the FULL or EMPTY output flags. Cascading is easily accomplished in the word-width direction, but is not possible in the word-depth direction.

The SN74ALS2232A is characterized for operation from 0°C to 70°C.

NT PACKAGE
(TOP VIEW)



FN PACKAGE
(TOP VIEW)



NC – No internal connection



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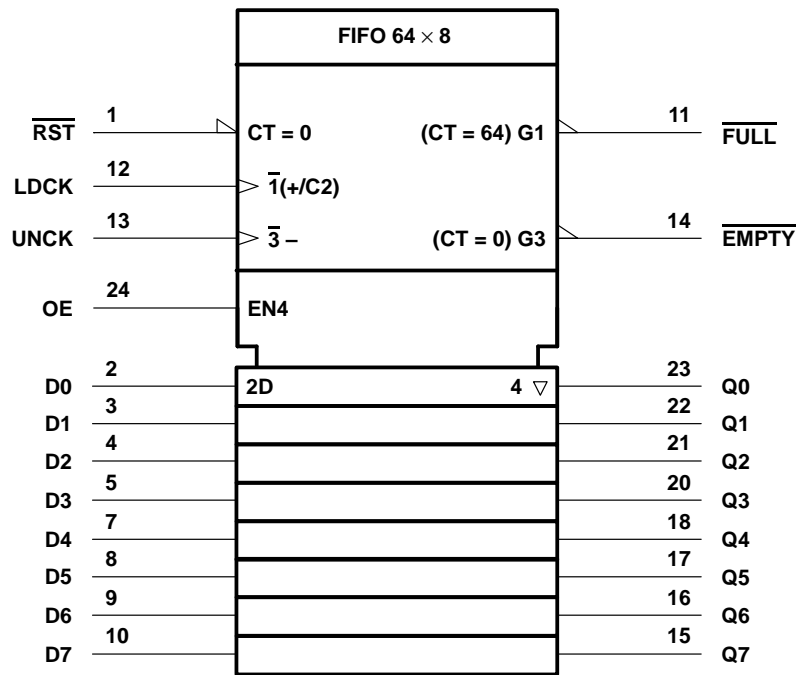
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logic symbol†



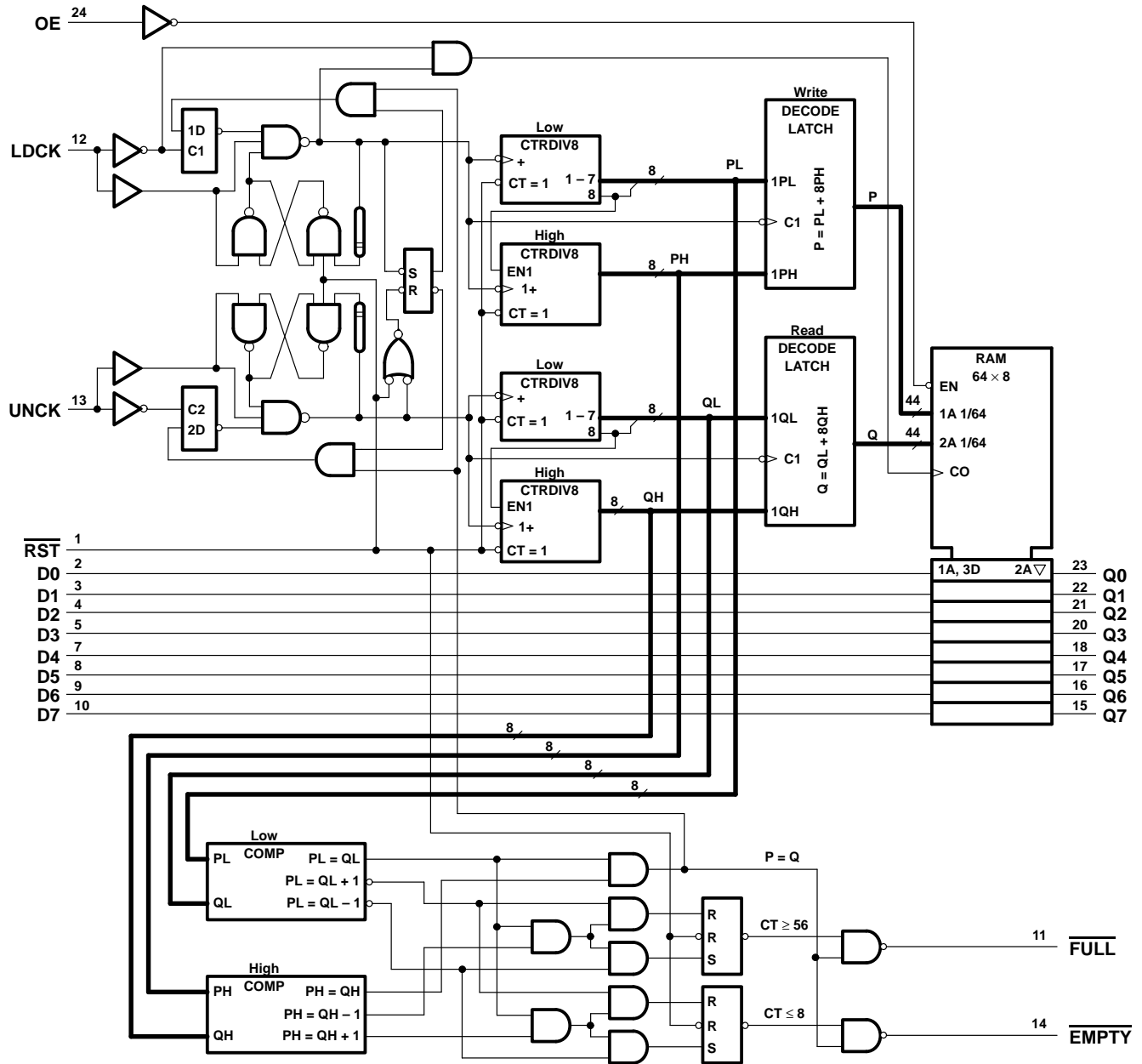
† This symbol is in accordance with ANSI/IEEE Standard 91-1984 and IEC Publication 617-12. The symbol is functionally accurate but does not show the details of implementation; for these, see the logic diagram. The symbol represents the memory as if it were controlled by a single counter whose content is the number of words stored at the time. Output data is invalid when the counter content (CT) is 0. Pin numbers shown are for the NT package.

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logic diagram (positive logic)

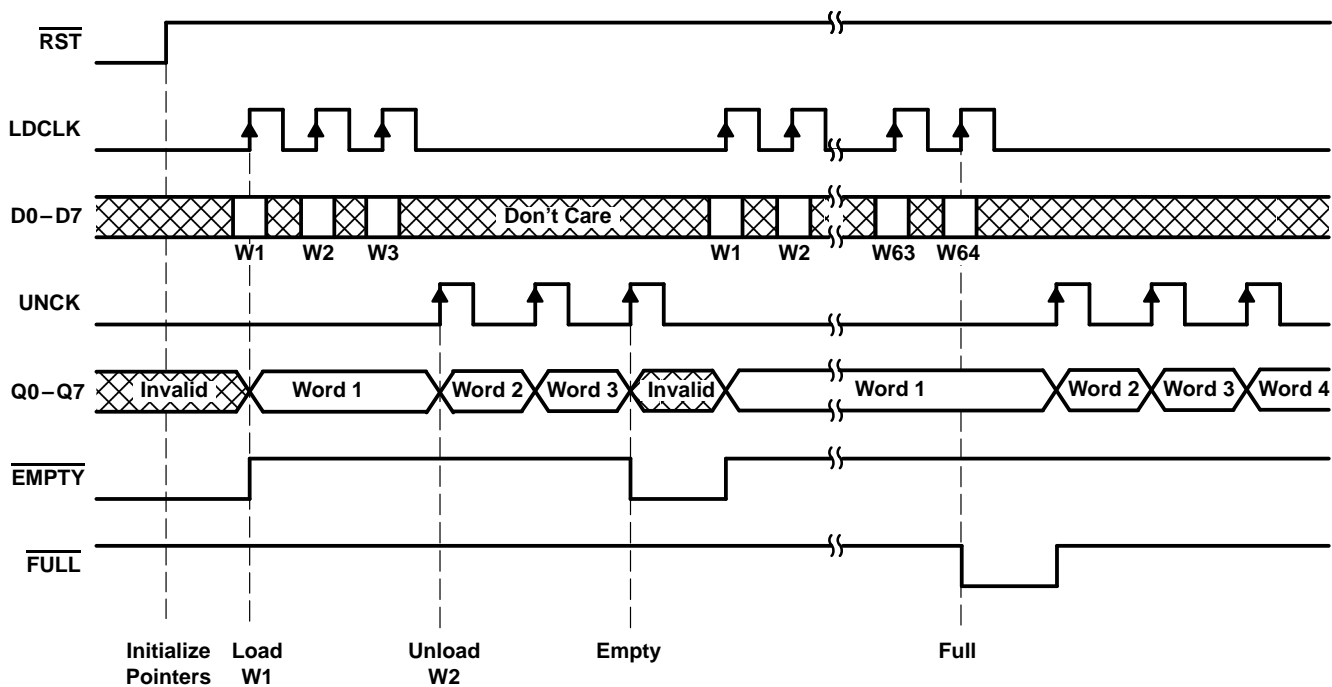


Pin numbers shown are for the NT package.

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timinig diagram



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| | |
|--|-----------------|
| Supply voltage, V _{CC} (see Note 1) | 7 V |
| Input voltage | 7 V |
| Voltage applied to a disabled 3-state output | 5.5 V |
| Operating free-air temperature range, T _A | 0°C to 70°C |
| Storage temperature range | – 65°C to 150°C |

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the “recommended operating conditions” section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to GND.

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recommended operating conditions

| | | | MIN | NOM | MAX | UNIT |
|--------------------|--|-------------|-----|-----|------|------|
| V _{CC} | Supply voltage | | 4.5 | 5 | 5.5 | V |
| V _{IH} | High-level input voltage | | 2 | | | V |
| V _{IL} | Low-level input voltage | | | | 0.8 | V |
| I _{OH} | High-level output current | Q outputs | | | –2.6 | mA |
| | | FULL, EMPTY | | | –0.4 | |
| I _{OL} | Low-level output current | Q outputs | | | 24 | mA |
| | | FULL, EMPTY | | | 8 | |
| f _{clock} | Clock frequency | LDCK, UNCK | 0 | | 40 | MHz |
| t _w | Pulse duration | RST low | 25 | | | ns |
| | | LDCK low | 13 | | | |
| | | LDCK high | 12 | | | |
| | | UNCK low | 13 | | | |
| | | UNCK high | 12 | | | |
| t _{su1} | Setup time, data before LDCK↑ | | 5 | | | ns |
| t _{su2} | Setup time, RST high (inactive) before LDCK↑ | | 5 | | | ns |
| t _h | Hold time, data after LDCK↑ | | 5 | | | ns |
| T _A | Operating free-air temperature | | 0 | | 70 | °C |

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITION† | | MIN | TYP‡ | MAX | UNIT |
|------------------|-------------|-------------------------------|---------------------------|---------------------|------|------|------|
| V _{IK} | | V _{CC} = 4.5 V, | I _I = –18 mA | | | –1.2 | V |
| V _{OH} | Q outputs | V _{CC} = 4.5 V, | I _{OH} = –2.6 mA | 2.4 | 3.2 | | V |
| | FULL, EMPTY | V _{CC} = MIN to MAX, | I _{OH} = 0.4 mA | V _{CC} – 2 | | | |
| V _{OL} | Q outputs | V _{CC} = 4.5 V | I _{OL} = 12 mA | | 0.25 | 0.4 | V |
| | | | I _{OL} = 24 mA | | 0.35 | 0.5 | |
| | FULL, EMPTY | V _{CC} = 4.5 V | I _{OL} = 4 mA | | 0.25 | 0.4 | |
| | | | I _{OL} = 8 mA | | 0.35 | 0.5 | |
| I _{OZH} | | V _{CC} = 5.5 V, | V _O = 2.7 V | | | 20 | μA |
| I _{OZL} | | V _{CC} = 5.5 V, | V _O = 0.4 V | | | –20 | μA |
| I _I | | V _{CC} = 5.5 V, | V _I = 7 V | | | 0.1 | mA |
| I _{IH} | | V _{CC} = 5.5 V, | V _I = 2.7 V | | | 20 | μA |
| I _{IL} | CLKs | V _{CC} = 5.5 V, | V _I = 0.4 V | | | –0.2 | mA |
| | Others | | | | | –0.1 | |
| I _{O§} | Q outputs | V _{CC} = 5.5 V, | V _O = 2.25 V | –20 | | –130 | mA |
| | FULL, EMPTY | | | –20 | | –112 | |
| I _{CC} | | V _{CC} = 5.5 V | | | 175 | 270 | mA |

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.



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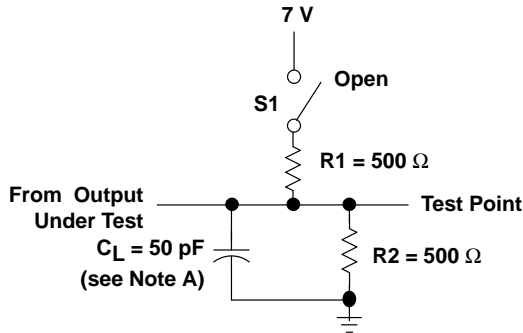
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switching characteristics (see Figure 1)

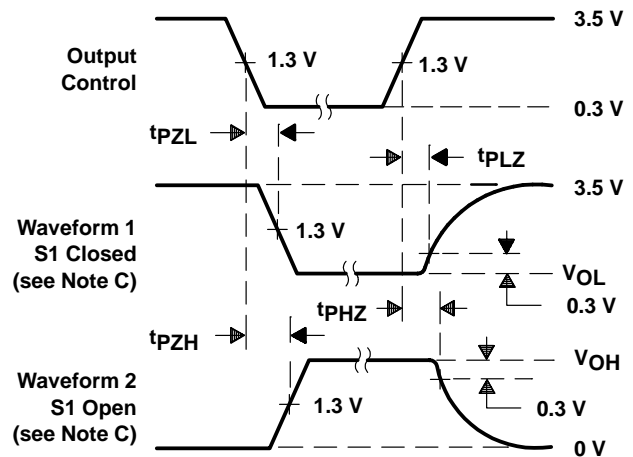
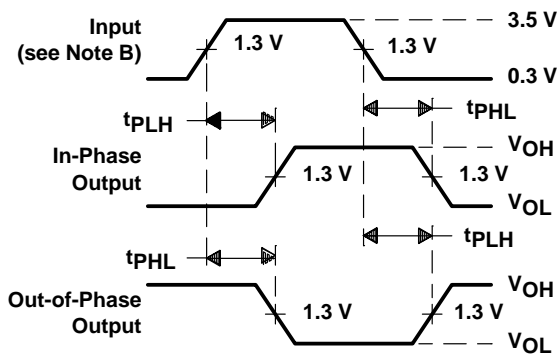
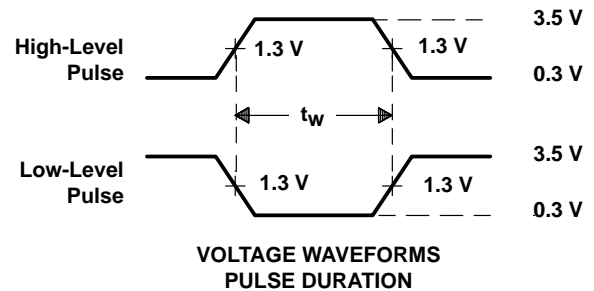
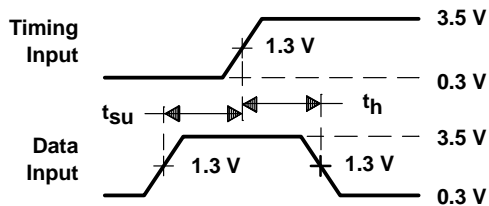
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 5 V, C _L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T _A = 25°C | | | V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T _A = 0°C to 70°C | | UNIT |
|------------------|-----------------|----------------|--|-----|-----|--|-----|------|
| | | | MAX | TYP | MAX | MIN | MAX | |
| f _{max} | LDCK, UNCK | | | | | 40 | | MHz |
| t _{pd} | LDCK↑ | Any Q | | 18 | 26 | | 30 | ns |
| | UNCK↑ | | | 18 | 24 | | 27 | |
| t _{PLH} | LDCK↑ | <u>EMPTY</u> | | 12 | 16 | | 18 | ns |
| t _{PHL} | UNCK↑ | | | 12 | 17 | | 20 | |
| t _{PHL} | <u>RST</u> ↓ | <u>EMPTY</u> | | 12 | 17 | | 20 | ns |
| t _{PHL} | LDCK↑ | <u>FULL</u> | | 16 | 21 | | 22 | ns |
| t _{PLH} | UNCK↑ | <u>FULL</u> | | 10 | 15 | | 18 | ns |
| | <u>RST</u> ↓ | | | 13 | 19 | | 23 | |
| t _{en} | OE↑ | Q | | 11 | 15 | | 17 | ns |
| t _{dis} | OE↓ | Q | | 11 | 17 | | 19 | ns |

PARAMETER MEASUREMENT INFORMATION



SWITCH POSITION TABLE

| TEST | S1 |
|------------------|--------|
| t _{PLH} | Open |
| t _{PHL} | Open |
| t _{PZH} | Open |
| t _{PZL} | Closed |
| t _{PHZ} | Open |
| t _{PLZ} | Closed |



- NOTES: A. C_L includes probe and jig capacitance.
 B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_0 = 50 \Omega$, $t_r \leq 2 \text{ ns}$, $t_f \leq 2 \text{ ns}$.
 C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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